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October 1996 Revised June 2005

74VCX16245

Low Voltage 16-Bit Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16245 contains sixteen non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. Each byte has separate 3-STATE control inputs which can be shorted together for full 16-bit operation. The T/\overline{R} inputs determine the direction of data flow through the device. The \overline{OE} inputs disable both the A and B ports by placing them in a high impedance state.

The 74VCX16245 is designed for low voltage (1.2V to 3.6V) V_{CC} applications with I/O compatibility up to 3.6V.

The 74VCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- ton

2.5 ns max for 3.0V to 3.6V $\rm V_{\rm CC}$

- Power-off high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL})

±24 mA @ 3.0V V_{CC}

- Uses proprietary noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:

Human body model > 2000V

Machine model >200V

Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver

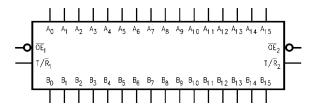
Ordering Code:

Order Number	Package Number	Package Description
74VCX16245G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74VCX16245MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol

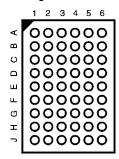


Connection Diagrams

Pin Assignment of TSSOP



Pin Assignment for FBGA



(Top Thru View)

Pin Descriptions

Pin Names Description	
OE _n	Output Enable Input (Active LOW)
T/R _n	Transmit/Receive Input
A ₀ -A ₁₅ B ₀ -B ₁₅	Side A Inputs or 3-STATE Outputs
B ₀ -B ₁₅	Side B Inputs or 3-STATE Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	B ₀	NC	T/R ₁	OE ₁	NC	A ₀
В	B ₂	B ₁	NC	NC	A ₁	A ₂
С	B ₄	B ₃	V _{CC}	V _{CC}	A ₃	A ₄
D	B ₆	B ₅	GND	GND	A ₅	A ₆
E	B ₈	B ₇	GND	GND	A ₇	A ₈
F	B ₁₀	B ₉	GND	GND	A ₉	A ₁₀
G	B ₁₂	B ₁₁	V _{CC}	V _{CC}	A ₁₁	A ₁₂
Н	B ₁₄	B ₁₃	NC	NC	A ₁₃	A ₁₄
J	B ₁₅	NC	T/R ₂	OE ₂	NC	A ₁₅

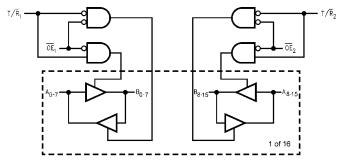
Truth Tables

lnı	outs	Outrot
OE ₁	T/R ₁	Outputs
L	L	Bus B ₀ -B ₇ Data to Bus A ₀ -A ₇
L	Н	Bus A ₀ –A ₇ Data to Bus B ₀ –B ₇
Н	Χ	HIGH Z State on A ₀ –A ₇ , B ₀ –B ₇

Inputs		0.1.1.
OE ₂	T/R ₂	Outputs
L	L	Bus B ₈ –B ₁₅ Data to Bus A ₈ –A ₁₅
L	Н	Bus A ₈ -A ₁₅ Data to Bus B ₈ -B ₁₅
Н	X	HIGH Z State on A ₈ -A ₁₅ , B ₈ -B ₁₅

- H = HIGH Voltage Level
- $\label{eq:Lambda} L = LOW\ Voltage\ Level \\ X = Immaterial\ (HIGH\ or\ LOW,\ inputs\ and\ I/O's\ may\ not\ float) \\ Z = High\ Impedance$

Logic Diagram



Absolute Maximum Ratings(Note 4)

-0.5V to +4.6V Supply Voltage (V_{CC}) DC Input Voltage (V_I) -0.5V to +4.6V Output Voltage (V_O) Outputs 3-STATE -0.5V to +4.6VOutputs Active (Note 5) -0.5 to $V_{CC} + 0.5V$ DC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA DC Output Diode Current (I_{OK}) $V_{O} < 0V$ -50 mA $V_{O} > V_{CC}$ +50 mA DC Output Source/Sink Current (I_{OH}/I_{OL}) $\pm 50 \text{ mA}$ DC V_{CC} or Ground Current per Supply Pin (I_{CC} or Ground) ±100 mA Storage Temperature Range (T_{STG}) -65°C to +150°C

Recommended Operating Conditions (Note 6)

Power Supply	
Operating	1.2V to 3.6V
Input Voltage	-0.3V to 3.6V
Output Voltage (V _O)	
Output in Active States	$\rm 0V$ to $\rm V_{CC}$
Output in 3-STATE	0.0V to 3.6V
Output Current in I _{OH} /I _{OL}	
$V_{CC} = 3.0V \text{ to } 3.6V$	±24 mA
$V_{CC} = 2.3V \text{ to } 2.7V$	±18 mA
$V_{CC} = 1.65V \text{ to } 2.3V$	±6 mA
$V_{CC} = 1.4V \text{ to } 1.6V$	±2 mA
V _{CC} = 1.2V	±100 μA
Free Air Operating Temperature (T _A)	-40°C to +85°C
Minimum Input Edge Rate (Δt/ΔV)	

Note 4: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 5: IO Absolute Maximum Rating must be observed.

 $V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$

Note 6: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.7 - 3.6	2.0		
*IH	Thorr Level input voltage		2.3 - 2.7	1.6		
			1.65 - 2.3	0.65 x V _{CC}		V
			1.4 - 1.6	0.65 x V _{CC}		•
			1.2	0.65 x V _{CC}		
V _{IL}	LOW Level Input Voltage		2.7 - 3.6		0.8	
IL.	, , , , , , , ,		2.3 - 2.7		0.7	
			1.65 - 2.3		0.35 x V _{CC}	V
			1.4 - 1.6		0.35 x V _{CC}	
			1.2		0.05 x V _{CC}	
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2		
		I _{OH} = -12 mA	2.7	2.2		
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.3 - 2.7	V _{CC} - 0.2		•
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -18 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \mu A$	1.65 - 2.3	V _{CC} - 0.2		•
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V _{CC} - 0.2		•
		I _{OH} = -2 mA	1.4	1.05		
		$I_{OH} = -100 \mu A$	1.2	V _{CC} - 0.2		•

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		I _{OL} = 12 mA	2.7		0.4	
		I _{OL} = 18 mA	3.0		0.4	
		I _{OL} = 24 mA	3.0		0.55	
		$I_{OL} = 100 \mu A$	2.3 - 2.7		0.2	
		I _{OL} = 12 mA	2.3		0.4	V
		I _{OL} = 18 mA	2.3		0.6	V
		$I_{OL} = 100 \mu A$	1.65 - 2.3		0.2	
		I _{OL} = 6 mA	1.65		0.3	
		$I_{OL} = 100 \mu A$	1.4 - 1.6		0.2	
		I _{OL} = 2 mA	1.4		0.35	
		I _{OL} = 100 μA	1.2		V _{CC} - 0.1	
l _l	Input Leakage Current	$0V \le V_I \le 3.6V$	1.2 - 3.6		±5.0	μΑ
loz	3-STATE Output Leakage	$0V \le V_O \le 3.6V$	1.2 - 3.6		±10	μА
		$V_I = V_{IH}$ or V_{IL}	1.2 - 3.0		±10	μΛ
l _{OFF}	Power Off Leakage Current	$0V \leq (V_I, V_O) \leq 3.6V$	0		10	μΑ
Icc	Quiescent Supply Current	V _I = V _{CC} or GND	1.2 - 3.6		20	μА
		$V_{CC} \le (V_I, V_O) \le 3.6V \text{ (Note 7)}$	1.2 - 3.6		±20	μΛ
ΔI_{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} - 0.6V	2.7 - 3.6		750	μА

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 8)

Symbol	Parameter	Conditions	V _{CC}	T _A = -40°	C to +85°C	Units	Figure
Symbol	raiailletei	Conditions	(V)	Min	Max	Units	Number
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	2.5		1
t _{PLH}			2.5 ± 0.2	1.0	3.0		Figures 1, 2
			1.8 ± 0.15	1.0	6.0	ns	.,_
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	12.0		Figures
			1.2	1.5	30		5, 6
t _{PZL}	Output Enable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.8		Ī
t _{PZH}			2.5 ± 0.2	1.0	4.9		Figures 1, 3, 4
			1.8 ± 0.15	1.5	9.3	ns	., -, -
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	18.6		Figures
			1.2	1.5	46.5		5, 7, 8
t _{PLZ}	Output Disable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.7		
t _{PHZ}			2.5 ± 0.2	1.0	4.2		Figures 1, 3, 4
			1.8 ± 0.15	1.5	7.6	ns	, -,
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	15.2		Figures
			1.2	1.5	38		5, 7, 8
t _{OSHL}	Output to Output	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3		0.5		
t _{OSLH}	Skew (Note 9)		2.5 ± 0.2		0.5		
			1.8 ± 0.15		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5		
			1.2		1.5		

Note 8: For $C_L = 50 pF$, add approximately 300ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dyna	Dynamic Switching Characteristics					
Symbol	Parameter	Conditions	V _{CC}	T _A = +25°C	Units	
•	- Tarameter		(V)	Typical		
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25		
			2.5	0.6	V	
			3.3	0.8		
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25		
			2.5	-0.6	V	
			3.3	-0.8		
V _{OHV}	Quiet Output Dynamic Valley VOH	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5		
			2.5	1.9	V	
			3.3	2.2		

Capacitance

Symbol Parameter		Conditions	$T_A = +25^{\circ}C$	Units
Cymbol	i diametei	Oditutions	Typical	Oille
C _{IN}	Input Capacitance	$V_{CC} = 1.8V, 2.5V, \text{ or } 3.3V, V_I = 0V \text{ or } V_{CC}$	6	pF
C _{I/O}	Output Capacitance	V _I = 0V, or V _{CC} , V _{CC} = 1.8V, 2.5V or 3.3V	7	pF
C _{PD}	Power Dissipation Capacitance	$V_{I} = 0V \text{ or } V_{CC}, F = 10 \text{ MHz}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20	pF

AC Loading and Waveforms (V $_{CC}$ 3.3V \pm 0.3V to 1.8V \pm 0.15V)

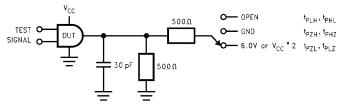


FIGURE 1. AC Test Circuit

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t_{PZL} , t_{PLZ}	6V at $V_{CC} = 3.3 \pm 0.3V$;
	V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V; 1.8V ± 0.15V
t _{PZH} , t _{PHZ}	GND

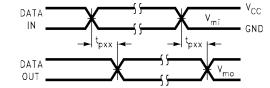


FIGURE 2. Waveform for Inverting and Non-inverting Functions

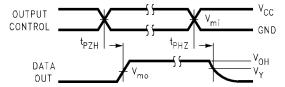


FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

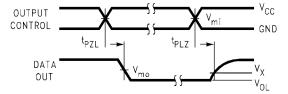
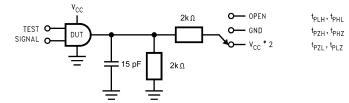


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V _{cc}		
	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2
V _X	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V
V _Y	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V

AC Loading and Waveforms (V $_{CC}$ 1.5V \pm 0.1V to 1.2V)



TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t_{PZL} , t_{PLZ}	V_{CC} x 2 at V_{CC} = 1.5 ± 0.1V

FIGURE 5. AC Test Circuit

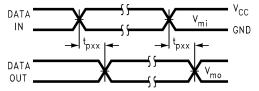


FIGURE 6. Waveform for Inverting and Non-Inverting Functions

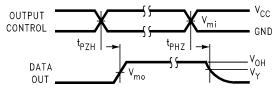


FIGURE 7. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

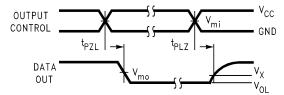
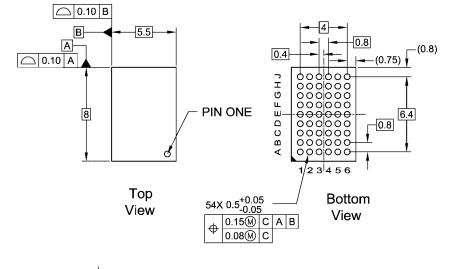
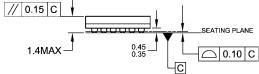


FIGURE 8. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V _{CC}	
Cymbol	1.5V ± 0.1V	
V _{mi}	V _{CC} /2	
V _{mo}	V _{CC} /2	
V _X	V _{OL} + 0.1V	
V_{Y}	V _{OH} – 0.1V	

Physical Dimensions inches (millimeters) unless otherwise noted



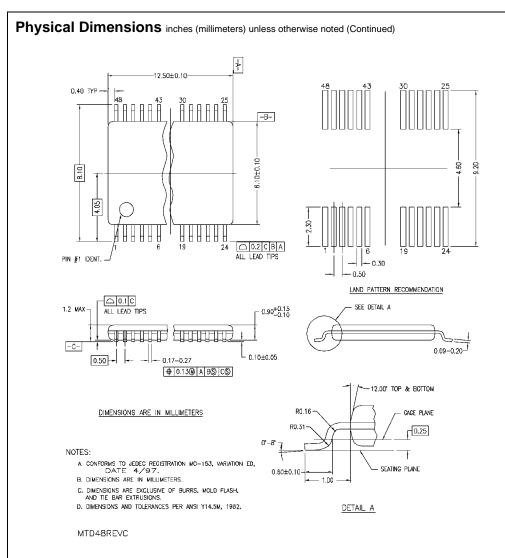


NOTES:

- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- **B. ALL DIMENSIONS IN MILLIMETERS**
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
 .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
 D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A



48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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